

National Semiconductor

LM6165/LM6265/LM6365 High Speed Operational Amplifier

General Description

The LM6165 family of high-speed amplifiers exhibits an excellent speed-power product in delivering 300 V/ μ s and 725 MHz GBW (stable for gains as low as +25) with only 5 mA of supply current. Further power savings and application convenience are possible by taking advantage of the wide dynamic range in operating supply voltage which extends all the way down to +5V.

These amplifiers are built with National's VIPTM (Vertically Integrated PNP) process which produces fast PNP transistors that are true complements to the already fast NPN devices. This advanced junction-isolated process delivers high speed performance without the need for complex and expensive dielectric isolation.

Features

- High slew rate 300 V/µs High GBW product 725 MHz Low supply current 5 mA Fast settling 80 ns to 0.1% Low differential gain < 0.1% Low differential phase < 0 1° Wide supply range 4.75V to 32V Stable with unlimited capacitive load Applications Video amplifier Wide-bandwidth signal conditioning
- Radar

Sonar

Connection Diagrams





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Order Number LM6165J/883 See NS Package Number J08A

Order Number LM6365M See NS Package Number M08A

Order Number LM6265N or LM6365N See NS Package Number N08E

LM6165/LM6265/LM6365

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

• •
36V
5) ±8V
$(V^+ - 0.7V)$ to $(V^ 7V)$
te 1) Continuous
260°C
215°C
220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Storage Temp Range	-65°C to +150°C
Max Junction Temperature (Note 2)	150°C
ESD Tolerance (Notes 6 and 7)	±700V

Operating Ratings

Temperature Range (Note 2) LM6165, LM6165J/883 LM6265 LM6365 Supply Voltage Range

 $\begin{array}{l} -55^{\circ}C \leq T_{J} \leq +125^{\circ}C \\ -25^{\circ}C \leq T_{J} \leq +85^{\circ}C \\ 0^{\circ}C \leq T_{J} \leq +70^{\circ}C \\ 4.75V \ to \ 32V \end{array}$

DC Electrical Characteristics

The following specifications apply for Supply Voltage = $\pm 15V$, $V_{CM} = 0$, $R_L \ge 100 \text{ k}\Omega$ and $R_S = 50\Omega$ unless otherwise noted. **Boldface** limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}C$.

Symbol	Parameter	Conditions	Тур	LM6165	LM6265	LM6365	Units
				Limit (Notes 3, 11)	Limit (Note 3)	Limit (Note 3)	
V _{OS}	Input Offset Voltage		1	3 4	3 4	6 7	mV Max
V _{OS} Drift	Input Offset Voltage Average Drift		3				μV/°(
łb	Input Bias Current		2.5	3 6	3 5	5 6	μA Max
l _{OS}	Input Offset Current		150	350 800	350 600	1500 1900	nA Max
l _{OS} Drift	Input Offset Current Average Drift		0.3				nA/°(
R _{IN}	Input Resistance	Differential	20				kΩ
C _{IN}	Input Capacitance		6.0				pF
A _{VOL}	Large Signal Voltage Gain (Note 9)	$V_{OUT} = \pm 10V,$ $R_L = 2 k\Omega$	10.5	7.5 5.0	7.5 6.0	5.5 5.0	V/mV Min
		$R_L = 10 k\Omega$	38			-	IVIIII
V _{CM}	Input Common-Mode Voltage Range	Supply = $\pm 15V$	+ 14.0	+ 13.9 + 13.8			V Min
			- 13.6	13.4 13.2	- 13.4 13.2	- 13.3 - 13.2	V Min
		Supply = $+5V$ (Note 4)	4.0	3.9 3.8	3.9 3.8	3.8 3.7	V Min
			1.4	1.6 1.8	1.6 1.8	1.7 1.8	V Max
CMRR	Common-Mode Rejection Ratio	$-10V \le V_{CM} \le +10V$	102	88 82	88 84	80 78	dB Min
PSRR	Power Supply Rejection Ratio	$\pm 10V \le V^{\pm} \le \pm 16V$	104	88 82	88 84	80 78	dB Min
Vo	Output Voltage Swing	Supply = $\pm 15V$, R _L = 2 k Ω	+ 14.2	+ 13.5 + 13.3	+ 13.5 + 13.3	+ 13.4 + 13.3	V Min
			- 13.4	- 13.0 - 12.7	- 13.0 12.8	- 12.9 - 12.8	V Min

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DC Electrical Characteristics (Continued)

The following specifications apply for Supply Voltage = $\pm 15V$, $V_{CM} = 0$, $R_L \ge 100 \text{ k}\Omega$ and $R_S = 50\Omega$ unless otherwise noted. **Boldface** limits apply for $T_A = T_J = T_{MIN}$ to T_{Max} ; all other limits $T_A = T_J = 25^{\circ}C$.

Symbol	Parameter Conditions		Тур	LM6165 Limit (Notes 3, 11)	LM6265 Limit (Note 3)	LM6365 Limit (Note 3)	Units
		Conditions					
V _O (Continued)	Output Voltage Swing (Continued)	Supply = $+5V$ R _L = 2 k Ω (Note 4)	4.2	3.5 3.3	3.5 3.3	3.4 3.3	V Min
	+t		1.3	1.7 2.0	1.7 1.9	1.8 1.9	V Max
	Output Short Circuit Current	Source	65	30 20	30 25	30 25	mA Min
	Sink	65	30 20	30 25	30 25	mA Min	
ls	Supply Current		5.0	6.5 6.8	6.5 6.7	6.8 6.9	mA Max

AC Electrical Characteristics

The following specifications apply for Supply Voltage = $\pm 15V$, $V_{CM} = 0$, $R_L \ge 100 k\Omega$ and $R_S = 50\Omega$ unless otherwise noted. **Boldface** limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}C$. (Note 5)

Symbol Para		Parameter Conditions	Тур	LM6165 Limit (Notes 3, 11)	LM6265 Limit (Note 3)	LM6365 Limit (Note 3)	Units
	Parameter						
GBW	Gain Bandwidth	F = 20 MHz	725	575 350	575	500	MHz
~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	Product	Supply = $\pm 5V$	500				Min
SR Slew Rate	Slew Rate	A _V = +25 (Note 8)	300	200 <b>180</b>	200	200	V/µs
		Supply = $\pm 5V$	200		0.00		- Min
PBW	Power Bandwidth Product	V _{OUT} = 20 V _{PP}	4.5		22		MHz
ts	Settling Time	10V Step to 0.1% A _V = $-25$ , R _L = 2 k $\Omega$	80		άr. C		ns
фm	Phase Margin	$A_{V} = +25$	45				Deg
AD	Differential Gain	NTSC, $A_V = +25$	<0.1				%
фD	Differential Phase	NTSC, $A_V = +25$	<0.1	-0-			Deg
e _{np-p}	Input Noise Voltage	F = 10 kHz	5		т. Т		nV/√Hz
i _{np-p}	Input Noise Current	F = 10 kHz	1.5				pA/√Hz

Note 1: Continuous short-circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Note 2: The typical junction-to-ambient thermal resistance of the molded plastic DIP (N) is 105°C/Watt, and the molded plastic SO (M) package is 155°C/Watt, and the cerdip (J) package is 125°C/Watt. All numbers apply for packages soldered directly into a printed circuit board.

Note 3: All limits guaranteed by testing or correlation.

Note 4: For single supply operation, the following conditions apply: V + = 5V, V - = 0V, V_{CM} = 2.5C, V_{OUT} = 2.5V. Pin 1 & Pin 8 (V_{OS} Adjust) are each connected to Pin 4 (V -) to realize maximum output swing. This connection will degrade V_{OS}.

#### Note 5: $C_L \leq 5 \, pF$ .

Note 6: In order to achieve optimum AC performance, the input stage was designed without protective clamps. Exeeding the maximum differential input voltage results in reverse breakdown of the base-emitter junction of one of the input transistors and probable degradation of the input parameters (especially V_{OS}, I_{OS}, and Noise).

Note 7: The average voltage that the weakest pin combinations (those involving Pin 2 or Pin 3) can withstand and still conform to the datasheet limits. The test circuit used consists of the human body model of 100 pF in series with 1500Ω.

Note 8:  $V_{IN} = 0.8V$  step. For supply =  $\pm 5V$ ,  $V_{IN} = 0.2V$  step.

Note 9: Voltage Gain is the total output swing (20V) divided by the input signal required to produce that swing.

Note 10: The voltage between V+ and either input pin must not exceed 36V.

Note 11: A military RETS electrical test specification is available on request. At the time of printing, the LM6165J/883 RETS spec complied with the Boldface limits in this column. The LM6165J/883 may also be procured as Standard Military Drawing #5962-8962501PA.



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# Typical Performance Characteristics (Continued) $R_L = 10 \ k\Omega, \ T_A = 25^{\circ}C$ unless otherwise specified

#### **Differential Gain (Note)**



**Differential Phase (Note)** 



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100

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Note: Differential gain and differential phase measured for four series LM6365 op amps configured with gain of +25 (each output attenuated by 96%), in series with an LM6321 buffer. Error added by LM6321 is negligible. Test performed using Tektronix Type 520 NTSC test system.

Step Response; Av = +25



#### TIME (50 (ns/div)



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## **Applications Tips**

The LM6365 is stable for gains of 25 or greater. The LM6361 and LM6364, specified in separate datasheets, are compensated versions of the LM6365. The LM6361 is unitygain stable, while the LM6364 is stable for gains as low as 5. The LM6361, and LM6364 have the same high slew rate as the LM6365, typically 300 V/ $\mu$ s.

To use the LM6365 for gains less than 25, a series resistorcapacitor network should be added between the input pins (as shown in the Typical Applications, Noise Gain Compensation) so that the high-frequency noise gain rises to at least 25.

Power supply bypassing will improve stability and transient response of the LM6365, and is recommended for every design. 0.01  $\mu$ F to 0.1  $\mu$ F ceramic capacitors should be

**Offset Voltage Adjustment** 

## **Typical Applications**

used (from each supply "rail" to ground); an additional 2.2  $\mu F$  to 10  $\mu F$  (tantalum) may be required for extra noise reduction.

Keep all leads short to reduce stray capacitance and lead inductance, and make sure ground paths are low-impedance, especially where heavier currents will be flowing. Stray capacitance in the circuit layout can cause signal coupling between adjacent nodes, and can cause circuit gain to unintentionally vary with frequency.

Breadboarded circuits will work best if they are built using generic PC boards with a good ground plane. If the op amps are used with sockets, as opposed to being soldered into the circuit, the additional input capacitance may degrade circuit performance.



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**Noise-Gain Compensation** 



 $R_X C_X \ge 1/(2\pi \bullet 25 \text{ MHz})$ [R1 + R_F (1 + R1/R2)] = 25 R_X



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